



## **Global Communication Semiconductors, LLC**

Corporate & Foundry  
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### **Sr. Device / Integration Engineer**

Job Req. #0712  
Department: RF and Power Technology  
Status: Full-Time / Salaried  
Shift: Day

#### **Job Description**

- Lead GaN HEMT device/process development and yield improvement efforts, including 0.5um, 0.25um, and 0.15um GaN HEMT processes.
- Responsible for device fabrication, characterization, and qualification.
- Support trouble-shooting, failure analysis, and yield improvement in related production processes.
- Interact with customers and manufacturing staff.
- Manage R&D projects.

#### **Job Requirements**

- Master's degree in Electrical Engineering. Physics or Materials Science
- 10+ years of industry experience in semiconductor wafer fab environment
- 4-6 years of direct hands-on experience in GaN HEMT technology